NPN VHF/UHF Transistor

The MMBTH10M3T5G device is a spin-off of our popular SOT-23 three-leaded device. It is designed for general purpose VHF/UHF applications and is housed in the SOT-723 surface mount package. This device is ideal for low-power surface mount applications where board space is at a premium.

Features

- Reduces Board Space
- This is a Halide-Free Device
- This is a Pb-Free Device

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector - Emitter Voltage	V _{CEO}	25	Vdc
Collector - Base Voltage	V _{CBO}	30	Vdc
Emitter - Base Voltage	V _{EBO}	3.0	Vdc

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board (Note 1) T _A = 25°C Derate above 25°C	P _D	265 2.1	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{ heta JA}$	470	°C/W
Total Device Dissipation Alumina Substrate, (Note 2) T _A = 25°C Derate above 25°C	P _D	640 5.1	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{ heta JA}$	195	°C/W
Junction and Storage Temperature	T _J , T _{stg}	-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

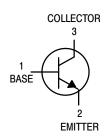
1

- 1. FR-5 = $1.0 \times 0.75 \times 0.062$ in.
- 2. Alumina = $0.4 \times 0.3 \times 0.024$ in. 99.5% alumina.



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MARKING DIAGRAM



SOT-723 CASE 631AA STYLE 1



AJ M Specific Device CodeDate Code

ORDERING INFORMATION

Device	Package	Shipping [†]
MMBTH10M3T5G	SOT-723 (Pb-Free)	8000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS			•	•	
Collector–Emitter Breakdown Voltage ($I_C = 1.0 \text{ mAdc}, I_B = 0$)	V _(BR) CEO	25	_	-	Vdc
Collector–Base Breakdown Voltage ($I_C = 100 \mu Adc, I_E = 0$)	V _(BR) CBO	30	-	-	Vdc
Emitter–Base Breakdown Voltage $(I_E = 10 \mu Adc, I_C = 0)$	V _{(BR)EBO}	3.0	-	-	Vdc
Collector Cutoff Current (V _{CB} = 25 Vdc, I _E = 0)	I _{CBO}	-	-	100	nAdc
Emitter Cutoff Current (V _{EB} = 2.0 Vdc, I _C = 0)	I _{EBO}	-	-	100	nAdc
ON CHARACTERISTICS	,		•	•	
DC Current Gain (I _C = 4.0 mAdc, V _{CE} = 10 Vdc)	h _{FE}	60	-	-	-
Collector–Emitter Saturation Voltage (I _C = 4.0 mAdc, I _B = 0.4 mAdc)	V _{CE(sat)}	-	-	0.5	Vdc
Base–Emitter On Voltage (I _C = 4.0 mAdc, V _{CE} = 10 Vdc)	V _{BE}	-	-	0.95	Vdc
SMALL-SIGNAL CHARACTERISTICS	1		JI	1	
Current-Gain - Bandwidth Product (I _C = 4.0 mAdc, V _{CE} = 10 Vdc, f = 100 MHz)	f _T	650	-	-	MHz
Collector–Base Capacitance $(V_{CB}=10\ Vdc,\ I_E=0,\ f=1.0\ MHz)$	C _{cb}	-	-	0.7	pF
Common–Base Feedback Capacitance (V _{CB} = 10 Vdc, I _E = 0, f = 1.0 MHz)	C _{rb}	_	_	0.65	pF
Collector Base Time Constant (I _C = 4.0 mAdc, V _{CB} = 10 Vdc, f = 31.8 MHz)	rb′C _c	-	-	9.0	ps

TYPICAL CHARACTERISTICS

COMMON-BASE y PARAMETERS versus FREQUENCY

(V_{CB} = 10 Vdc, I_{C} = 4.0 mAdc, T_{A} = 25°C)

y_{ib}, INPUT ADMITTANCE

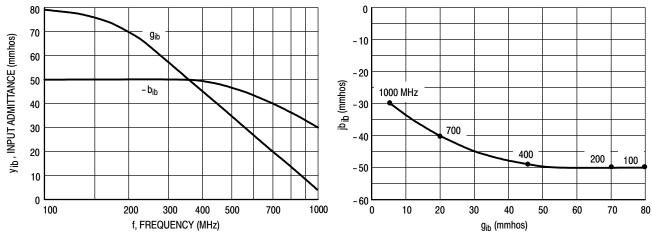


Figure 1. Rectangular Form

Figure 2. Polar Form

y_{fb}, FORWARD TRANSFER ADMITTANCE

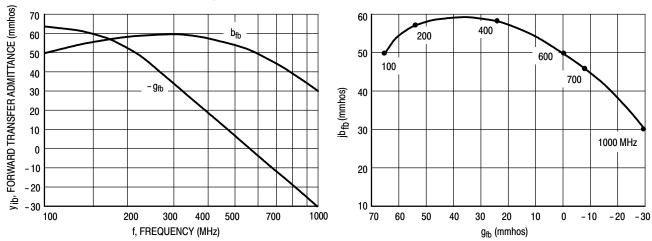


Figure 3. Rectangular Form

Figure 4. Polar Form

TYPICAL CHARACTERISTICS

COMMON-BASE y PARAMETERS versus FREQUENCY

(V_{CB} = 10 Vdc, I_{C} = 4.0 mAdc, T_{A} = 25°C)

y_{rb}, REVERSE TRANSFER ADMITTANCE

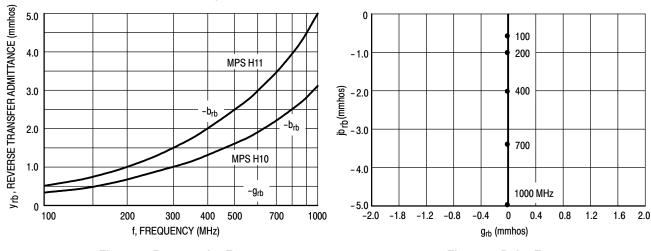


Figure 5. Rectangular Form

Figure 6. Polar Form

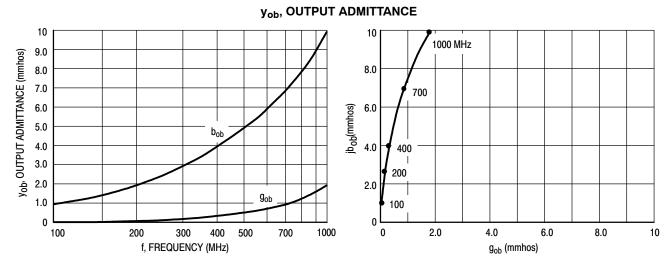


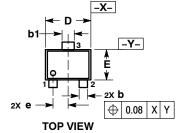
Figure 7. Rectangular Form

Figure 8. Polar Form

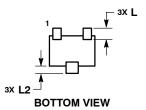


SOT-723 CASE 631AA-01 ISSUE D

DATE 10 AUG 2009









STYLE 1: PIN 1. BASE 2. EMITTER 3. COLLECTOR STYLE 2: PIN 1. ANODE 2. N/C 3. CATHODE STYLE 3: PIN 1. ANODE 2. ANODE 3. CATHODE

STYLE 4: PIN 1. CATHODE 2. CATHODE 3. ANODE

STYLE 5: PIN 1. GATE 2. SOURCE 3. DRAIN

NOTES:

- NOTES.

 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.

 2. CONTROLLING DIMENSION: MILLIMETERS.

 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD
- FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
- DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.

	MILLIMETERS			
DIM	MIN	NOM	MAX	
Α	0.45	0.50	0.55	
b	0.15	0.21	0.27	
b1	0.25	0.31	0.37	
С	0.07	0.12	0.17	
D	1.15	1.20	1.25	
E	0.75	0.80	0.85	
е	0.40 BSC			
ΗE	1.15	1.20	1.25	
L	0.29 REF			
L2	0.15	0.20	0.25	

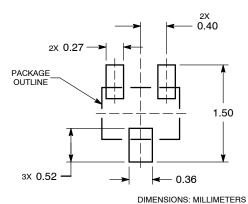
GENERIC MARKING DIAGRAM*



= Specific Device Code XX Μ = Date Code

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G", may or not be present.

RECOMMENDED SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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